



Surface Mount Schottky Barrier Rectifier

Reverse Voltage - 20 to 200V

Forward Current - 5.0A

FEATURES

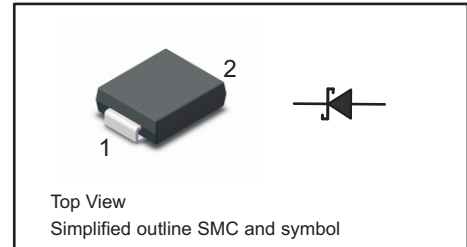
- Metal silicon junction, majority carrier conduction
- For surface mounted applications
- Low power loss, high efficiency
- High forward surge current capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

MECHANICAL DATA

- Case: SMC
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.22g / 0.0077oz

PINNING

PIN	DESCRIPTION
1	Cathode
2	Anode



Absolute Maximum Ratings and Electrical characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz resistive or inductive load, for capacitive load, derate by 20 %

Parameter	Symbols	SS52C	SS54C	SS56C	SS58C	SS510C	SS512C	SS515C	SS520C	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	20	40	60	80	100	120	150	200	V
Maximum RMS voltage	V_{RMS}	14	28	42	56	70	84	105	140	V
Maximum DC Blocking Voltage	V_{DC}	20	40	60	80	100	120	150	200	V
Maximum Average Forward Rectified Current @ Fig.1	$I_{F(AV)}$	5.0								A
Peak Forward Surge Current, 8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	120								A
Peak Forward Surge Current, 1.0ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	240								A
I^2t Rating for fusing (3ms ≤ t ≤ 8.3ms)	I^2t	59.7								A ² S
Max Instantaneous Forward Voltage at 5 A	V_F	0.55		0.70		0.85		0.95		V
Maximum DC Reverse Current $T_a = 25^\circ\text{C}$ at Rated DC Reverse Voltage $T_a = 100^\circ\text{C}$	I_R	1.0 50								mA
Typical Junction Capacitance ⁽¹⁾	C_j	270		220		160		100	80	pF
Typical Thermal Resistance ⁽²⁾	$R_{\theta JA}$ $R_{\theta JC}$ $R_{\theta JL}$	37 10 13								°C/W
Operating Junction Temperature Range	T_j	-55 ~ +125								°C
Storage Temperature Range	T_{stg}	-55 ~ +150								°C

(1) Measured at 1 MHz and applied reverse voltage of 4 V D.C

(2) P.C.B. mounted with 1.5" X 1.5" (3.81 X 3.81 cm) copper pad areas.



Fig.1 Forward Current Derating Curve

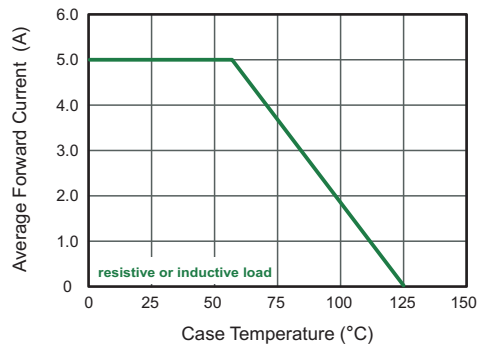


Fig.2 Typical Reverse Characteristics

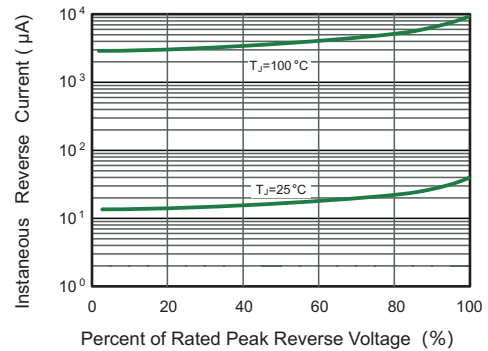


Fig.3 Typical Forward Characteristic

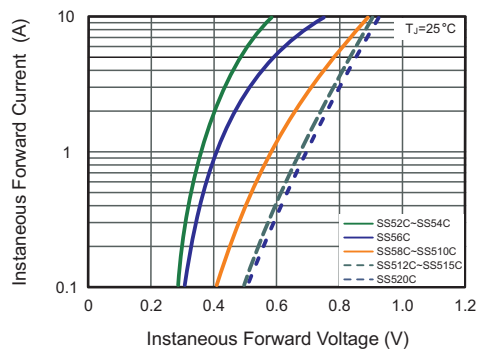


Fig.4 Typical Junction Capacitance

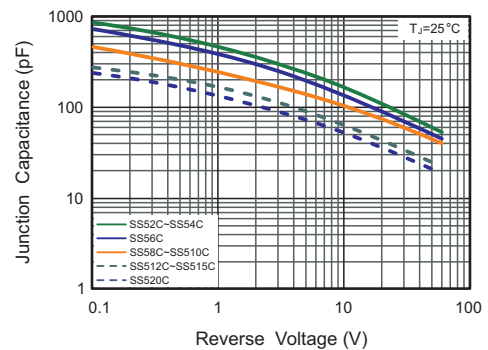
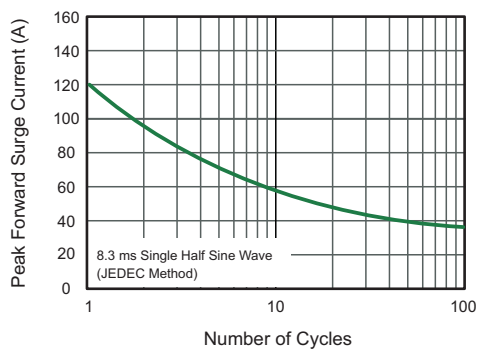


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current

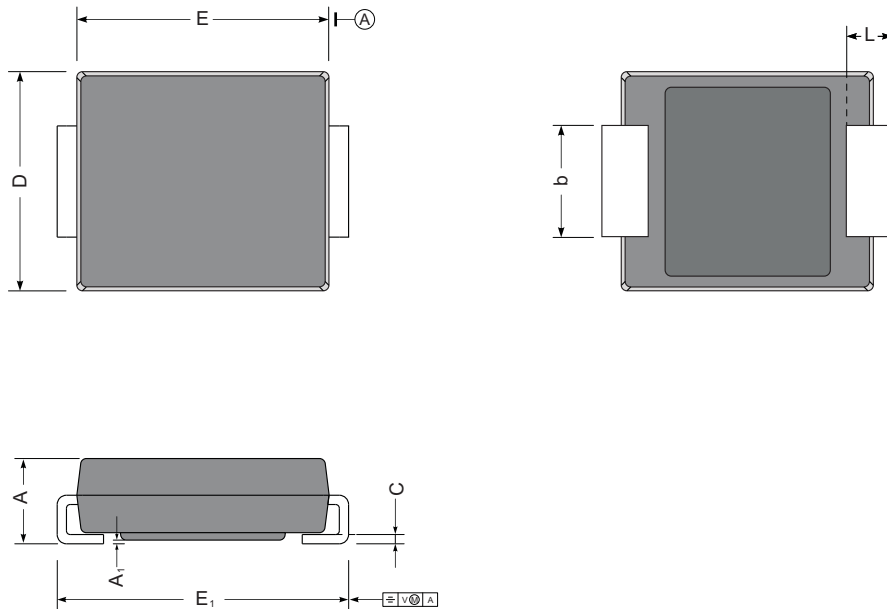




PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

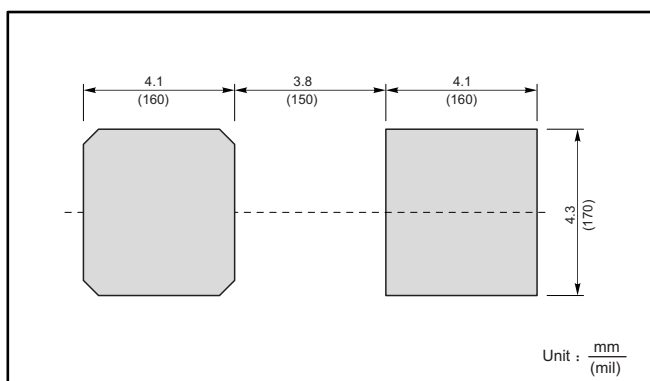
SMC



SMC mechanical data

UNIT		A	E	D	E ₁	A ₁	C	L	b
mm	max	2.62	7.0	6.2	8.0	0.21	0.31	1.6	3.25
	min	2.00	6.5	5.6	7.6	0.05	0.15	0.9	2.75
mil	max	103	276	244	315	8.3	12	63	128
	min	79	256	220	299	2.0	5.9	35	108

The recommended mounting pad size



Marking

Type number	Marking code
SS52C	SS52
SS54C	SS54
SS56C	SS56
SS58C	SS58
SS510C	SS510
SS512C	SS512
SS515C	SS515
SS520C	SS520



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